

**CMUT2907A**  
**ULTRAmi™ SURFACE MOUNT**  
**PNP SILICON TRANSISTOR**



# Central™

**Semiconductor Corp.**

**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CMUT2907A type is an PNP silicon transistor manufactured by the epitaxial planar process, epoxy molded in an ULTRAmi™ surface mount package, designed for small signal general purpose and switching applications.  
 Marking Code is FC2.

**MAXIMUM RATINGS:** (T<sub>A</sub>=25°C)

	<b>SYMBOL</b>		<b>UNITS</b>
Collector-Base Voltage	V <sub>CBO</sub>	60	V
Collector-Emitter Voltage	V <sub>CEO</sub>	60	V
Emitter-Base Voltage	V <sub>EBO</sub>	5.0	V
Collector Current	I <sub>C</sub>	600	mA
Power Dissipation	P <sub>D</sub>	250	mW
Operating and Storage			
Junction Temperature	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C
Thermal Resistance	θ <sub>JA</sub>	500	°C/W

**ELECTRICAL CHARACTERISTICS:** (T<sub>A</sub>=25°C unless otherwise noted)

<b>SYMBOL</b>	<b>TEST CONDITIONS</b>	<b>MIN</b>	<b>MAX</b>	<b>UNITS</b>
I <sub>CBO</sub>	V <sub>CB</sub> =50V		10	nA
I <sub>CBO</sub>	V <sub>CB</sub> =50V, T <sub>A</sub> =125°C		10	µA
I <sub>CEV</sub>	V <sub>CE</sub> =30V, V <sub>BE</sub> =0.5V		50	nA
BV <sub>CBO</sub>	I <sub>C</sub> =10µA	60		V
BV <sub>CEO</sub>	I <sub>C</sub> =10mA	60		V
BV <sub>EBO</sub>	I <sub>E</sub> =10µA	5.0		V
V <sub>CE(SAT)</sub>	I <sub>C</sub> =150mA, I <sub>B</sub> =15mA		0.4	V
V <sub>CE(SAT)</sub>	I <sub>C</sub> =500mA, I <sub>B</sub> =50mA		1.6	V
V <sub>BE(SAT)</sub>	I <sub>C</sub> =150mA, I <sub>B</sub> =15mA		1.3	V
V <sub>BE(SAT)</sub>	I <sub>C</sub> =500mA, I <sub>B</sub> =50mA		2.6	V
h <sub>FE</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =0.1mA	75		
h <sub>FE</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =1.0mA	100		
h <sub>FE</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =10mA	100		
h <sub>FE</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =150mA	100	300	
h <sub>FE</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =500mA	50		

R0 ( 30-May 2001)

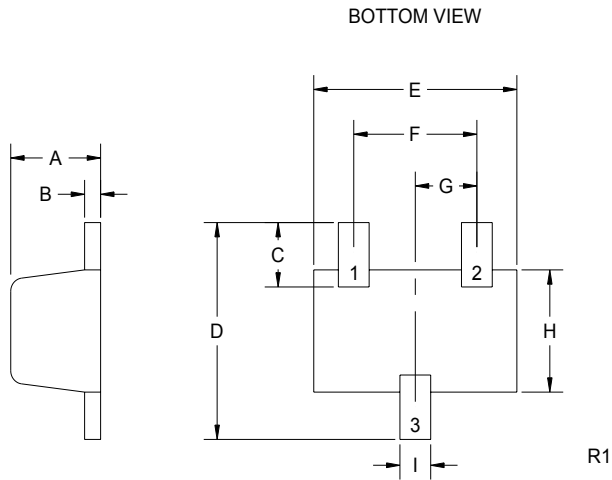
**ELECTRICAL CHARACTERISTICS: Continued**

<u>SYMBOL</u>	<u>TEST CONDITIONS</u>	<u>MIN</u>	<u>MAX</u>	<u>UNITS</u>
$f_T$	$V_{CE}=20V, I_C=50mA, f=100MHz$	200		MHz
$C_{ob}$	$V_{CB}=10V, I_E=0, f=1.0MHz$		8.0	pF
$C_{ib}$	$V_{BE}=2.0V, I_C=0, f=1.0MHz$		30	pF
$t_{on}$	$V_{CC}=30V, V_{BE}=0.5V, I_C=150mA, I_{B1}=15mA$		45	ns
$t_d$	$V_{CC}=30V, V_{BE}=0.5V, I_C=150mA, I_{B1}=15mA$		10	ns
$t_r$	$V_{CC}=30V, V_{BE}=0.5V, I_C=150mA, I_{B1}=15mA$		40	ns
$t_{off}$	$V_{CC}=6.0V, I_C=150mA, I_{B1}=I_{B2}=15mA$		100	ns
$t_s$	$V_{CC}=6.0V, I_C=150mA, I_{B1}=I_{B2}=15mA$		80	ns
$t_f$	$V_{CC}=6.0V, I_C=150mA, I_{B1}=I_{B2}=15mA$		30	ns

**MECHANICAL OUTLINE - SOT-523**

SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.025	0.029	0.63	0.73
B	0.004	0.005	0.10	0.13
C	0.015	0.019	0.39	0.49
D	0.061	0.065	1.55	1.65
E	0.061	0.065	1.55	1.65
F	0.039	0.040	0.98	1.02
G	0.019	0.020	0.48	0.52
H	0.033	0.037	0.83	0.93
I	0.009	0.010	0.23	0.25

SOT-523 (REV: R1)



LEAD CODE:

- 1) Base
- 2) Emitter
- 3) Collector